IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Atty. Docket No.:

002372.00043

KANAYA et al.

Serial No.:

TBA

Group Art Unit:

TBA

Filed:

June 25, 2003

Examiner:

TBA

For:

Semiconductor Device Having Ferroelectric Capacitor and Hydrogen Barrier

Film and Manufacturing Method Thereof

PRELIMINARY AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Preliminary to the examination of the above-identified application, kindly amend the application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 8 of this paper.

Amendments to the Title begin on page 9 of this paper.

Remarks begin on page 10 of this paper.